

KSA1381

CRT Display, Video Output

• High Collector-Emitter Breakdown Voltage : V_{CEO} = -300V • Low Reverse Transfer Capacitance : C_{re} = 2.3pF at V_{CB} = -30V



PNP Epitaxial Silicon Transistor

Absolute Maximum Ratings T_C=25°C unless otherwise noted

Symbol	Parameter	Ratings	Units	
V _{CBO}	Collector-Base Voltage	- 300	V	
V _{CEO}	Collector-Emitter Voltage	- 300	V	
V _{EBO}	Emitter-Base Voltage	- 5	V	
I _C	Collector Current (DC)	- 100	mA	
I _{CP}	Collector Current (Pulse)	- 200	mA	
P _C	Collector Dissipation (T _C =25°C)	7	W	
P _C	Collector Dissipation (T _a =25°C)	1.2	W	
T _J	Junction Temperature	150	°C	
T _{STG}	Storage Temperature	- 55 ~ 150	°C	

Electrical Characteristics $T_C=25$ °C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
BV _{CBO}	Collector-Base Breakdown Voltage	$I_C = -10\mu A, I_E = 0$	- 300			V
BV _{CEO}	Collector-Emitter Breakdown Voltage	$I_C = -1 \text{mA}, I_B = 0$	- 300			V
BV _{EBO}	Emitter-Base Breakdown Voltage	$I_E = -10\mu A, I_C = 0$	- 5			V
I _{CBO}	Collector Cut-off Current	$V_{CB} = -200V, I_{E} = 0$			- 0.1	μΑ
I _{EBO}	Emitter Cut-off Current	$V_{EB} = -4V, I_{C} = 0$			- 0.1	μΑ
h _{FE}	DC Current Gain	$V_{CE} = -10V, I_{C} = -10mA$	40		320	
V _{CE} (sat)	Collector-Emitter Saturation Voltage	$I_C = -20 \text{mA}, I_B = -2 \text{mA}$			- 0.6	V
V _{BE} (sat)	Base-Emitter Saturation Voltage	$I_C = -20 \text{mA}, I_B = -2 \text{mA}$			- 1	V
f _T	Current Gain Bandwidth Product	$V_{CE} = -30V, I_{C} = -10mA$		150		MHz
C _{ob}	Output Capacitance	V _{CB} = - 30V, f = 1MHz		3.1		pF
C _{re}	Reverse Transfer Capacitance	V _{CB} = - 30V, f = 1MHz		2.3		pF

h_{FE} Classification

Classification	С	D	Ш	F
h _{FE}	40 ~ 80	60 ~ 120	100 ~ 200	160 ~ 320

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Typical Characteristics

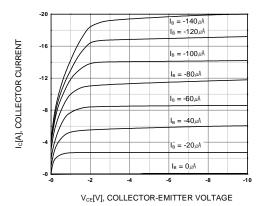


Figure 1. Static Characteristic

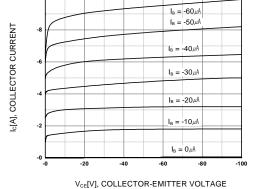


Figure 2. Static Characteristic

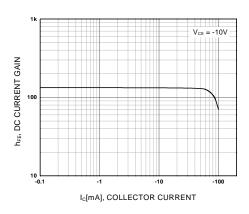


Figure 3. DC current Gain

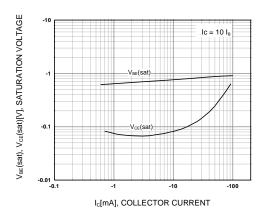


Figure 4. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage

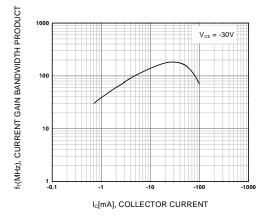


Figure 5. Current Gain Bandwidth Product

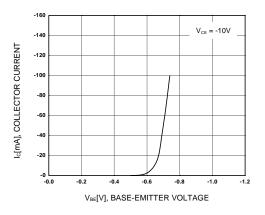


Figure 6. Base-Emitter On Voltage

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Typical Characteristics (Continued)

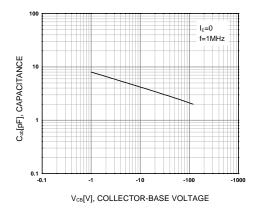


Figure 7. Collector Output Capacitance

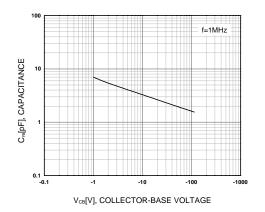


Figure 8. Reverse Transfer Capacitance

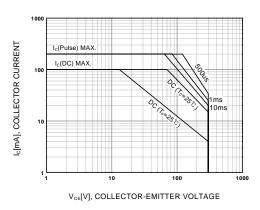


Figure 9. Safe Operating Area

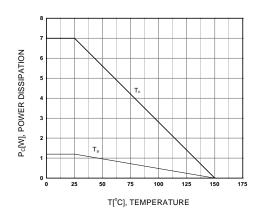
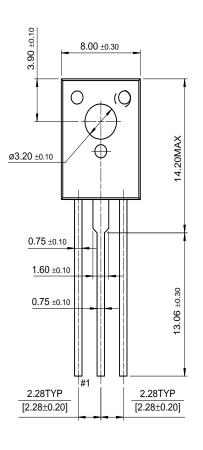


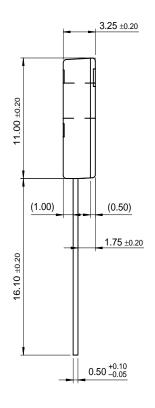
Figure 10. Power Derating

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Package Demensions

TO-126







Dimensions in Millimeters

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Advance Information Formative or In Design		This datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
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KSA1381

PNP Epitaxial Silicon Transistor

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Features

CRT Display, Video Output

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Product status/pricing/packaging

BUY

Product	Product status	Pb-free Status	Pricing*	Package type	Leads	Packing method	Package Marking Convention**
KSA1381ES	Full Production	Full Production	\$0.151	<u>TO-126</u>	3	BULK	Line 1: \$Y (Fairchild logo) & 3 (3-Digit Date Code) Line 3: A1381-C
KSA1381ESTSSTU	Full Production	Full Production	\$0.151	<u>TO-126</u>	3	RAIL	Line 1: \$Y (Fairchild logo) & 3 (3-Digit Date Code) Line 3: A1381-C
KSA1381ESTSTU	Full Production	Full Production	\$0.151	<u>TO-126</u>	3	RAIL	Line 1: \$Y (Fairchild logo) & 3 (3-Digit Date Code) Line 3: A1381-C
							Line 1: \$Y (Fairchild logo)

KSA1381ESTU Full Production	Full Production	\$0.151	<u>TO-126</u>	3		& 3 (3-Digit Date Code) <u>Line 3:</u> A1381-C
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^{*} Fairchild 1,000 piece Budgetary Pricing

** A sample button will appear if the part is available through Fairchild's on-line samples program. If there is no sample button, please contact a Fairchild distributor to obtain samples



Indicates product with Pb-free second-level interconnect. For more information click here.

Package marking information for product KSA1381 is available. Click here for more information.

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Models

Package & leads	Condition	Condition Temperature range Vcc range		Software version	Revision date		
PSPICE							
TO-126-3 <u>Electrical</u> -55°C to 150°C		0V to 10V	OrCAD 10.3	May 11, 2007			

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Qualification Support

Click on a product for detailed qualification data

Product
KSA1381ES
KSA1381ESTSSTU
KSA1381ESTSTU
KSA1381ESTU

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